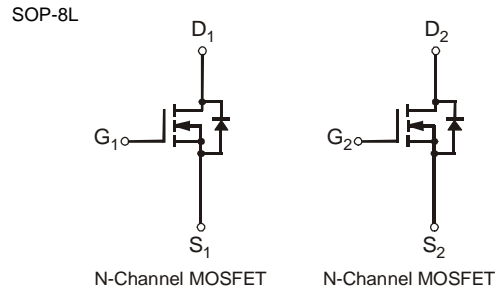
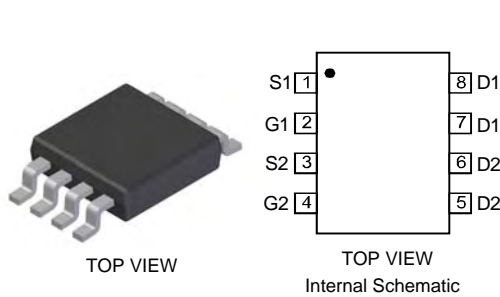


Features

- Dual N-Channel MOSFET
- Low On-Resistance
 - 26mΩ @ V_{GS} = 4.5V
 - 36mΩ @ V_{GS} = 2.5V
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **Lead Free By Design/RoHS Compliant (Note 2)**
- **"Green" Device (Note 4)**
- **Qualified to AEC-Q 101 Standards for High Reliability**

Mechanical Data

- Case: SOP-8L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals Connections: See Diagram
- Terminals: Finish - Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.072 grams (approximate)



Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Value | Units |
|-------------------------------|------------------|--------------|--|
| Drain-Source Voltage | V _{DSS} | 20 | V |
| Gate-Source Voltage | V _{GSS} | ±12 | V |
| Drain Current (Note 1) | I _D | 7.0 5.6 | A |
| | | Steady State | T _A = 25°C T _A = 70°C |
| Pulsed Drain Current (Note 3) | I _{DM} | 30 | A |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 1) | P _D | 2 | W |
| Thermal Resistance, Junction to Ambient | R _{θJA} | 62.5 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics @T_A = 25°C unless otherwise specified

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|-------------------------------------|---------------------|-----|----------|----------|------|--|
| OFF CHARACTERISTICS (Note 5) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 20 | — | — | V | V _{GS} = 0V, I _D = 250μA |
| Zero Gate Voltage Drain Current | I _{DSS} | — | — | 1 | μA | V _{DS} = 20V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | — | — | ±100 | nA | V _{GS} = ±12V, V _{DS} = 0V |
| ON CHARACTERISTICS (Note 5) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | 0.6 | — | 1.2 | V | V _{DS} = V _{GS} , I _D = 250μA |
| Static Drain-Source On-Resistance | R _{DS(ON)} | — | 19 26 | 26 36 | mΩ | V _{GS} = 4.5V, I _D = 6.0A V _{GS} = 2.5V, I _D = 5.2A |
| Forward Transfer Admittance | g _{fs} | — | 12 | — | ms | V _{DS} = 10V, I _D = 6.0A |
| Diode Forward Voltage (Note 5) | V _{SD} | 0.5 | — | 1.2 | V | V _{GS} = 0V, I _S = 1.7A |
| DYNAMIC CHARACTERISTICS | | | | | | |
| Input Capacitance | C _{iss} | — | 562 | — | pF | V _{DS} = 10V, V _{GS} = 0V f = 1.0MHz |
| Output Capacitance | C _{oss} | — | 75 | — | pF | |
| Reverse Transfer Capacitance | C _{rss} | — | 65 | — | pF | |

- Notes:
1. Device mounted on 2 oz. Copper pads on FR-4 PCB.
 2. No purposefully added lead.
 3. Pulse width ≤10μs, Duty Cycle ≤1%.
 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 5. Short duration pulse test used to minimize self-heating effect.

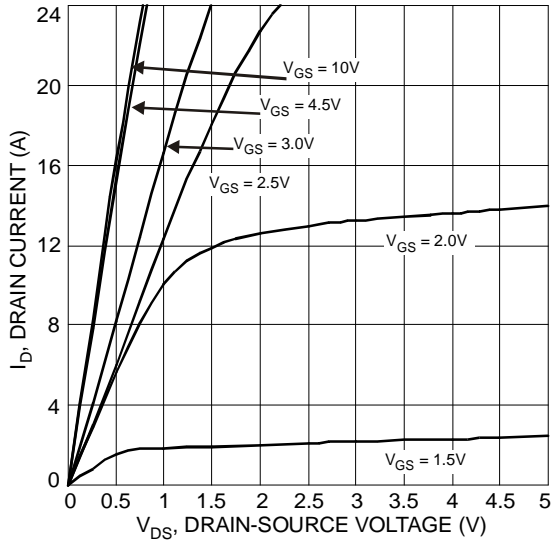


Fig. 1 Typical Output Characteristics

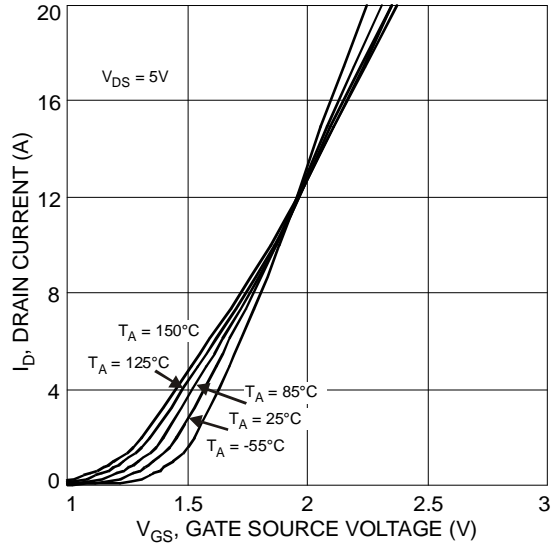


Fig. 2 Typical Transfer Characteristics

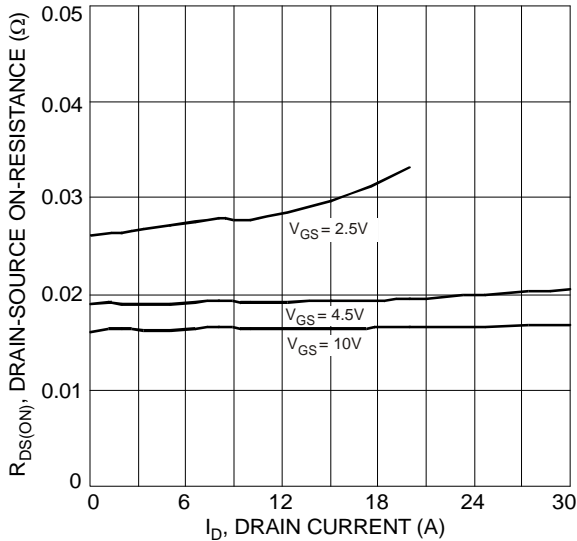


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

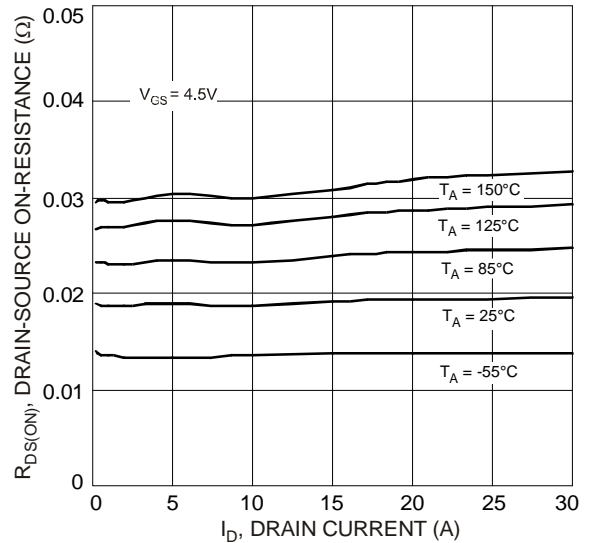


Fig. 4 Typical Drain-Source On-Resistance vs. Drain Current and Temperature

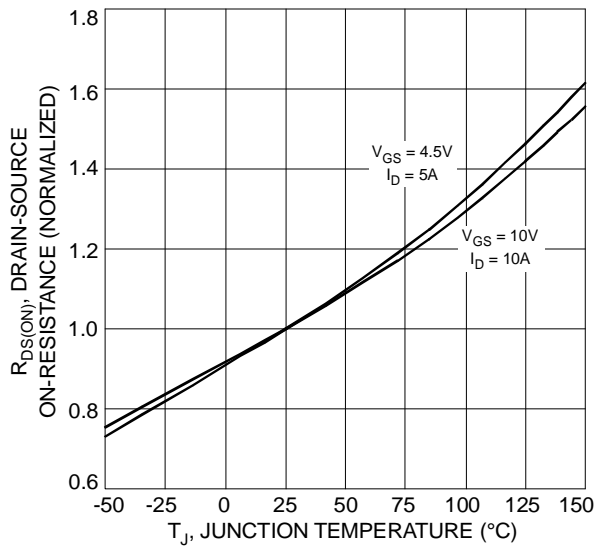


Fig. 5 On-Resistance Variation with Temperature

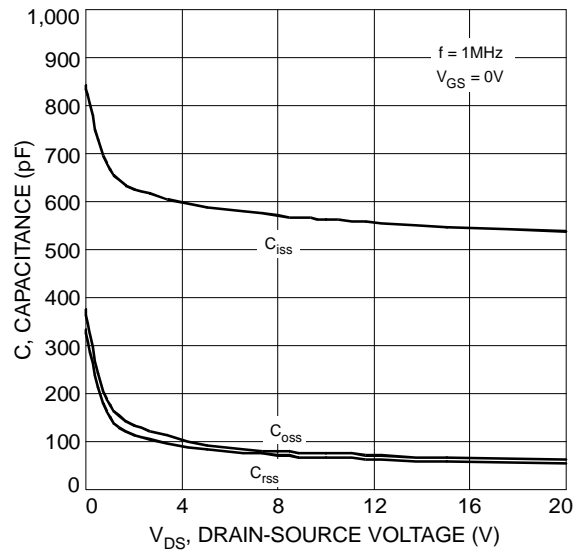


Fig. 6 Typical Capacitance

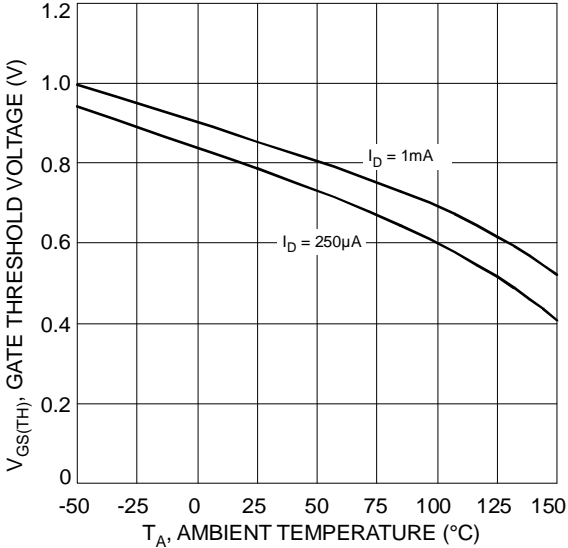


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

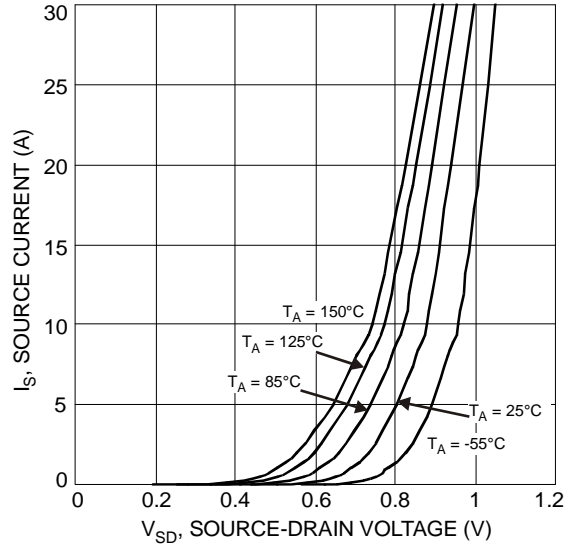


Fig. 8 Diode Forward Voltage vs. Current

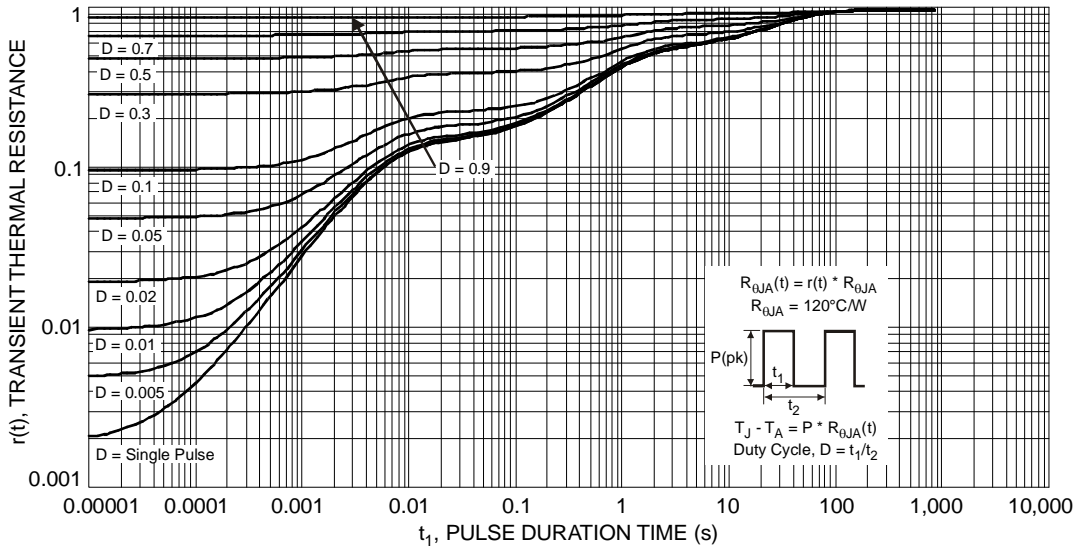


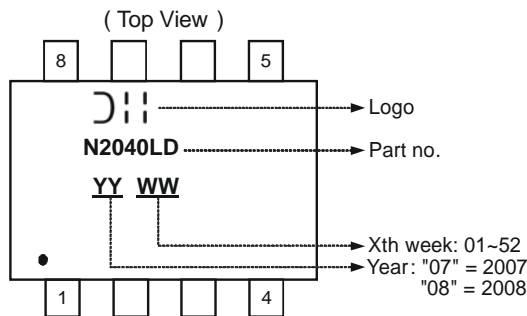
Fig. 9 Transient Thermal Response

Ordering Information (Note 6)

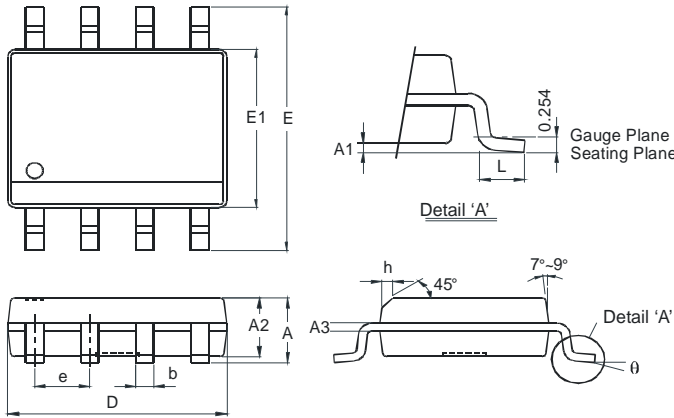
| Part Number | Case | Packaging |
|---------------|--------|------------------|
| DMN2040LSD-13 | SOP-8L | 2500/Tape & Reel |

Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information

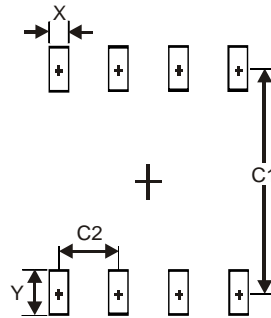


Package Outline Dimensions



| SOP-8L | | |
|-----------------------------|----------|------|
| Dim | Min | Max |
| A | - | 1.75 |
| A1 | 0.08 | 0.25 |
| A2 | 1.40 | 1.50 |
| A3 | 0.20 Typ | |
| b | 0.3 | 0.5 |
| D | 4.85 | 4.95 |
| E | 5.90 | 6.10 |
| E1 | 3.80 | 3.90 |
| e | 1.27 Typ | |
| h | - | 0.35 |
| L | 0.60 | 0.80 |
| θ | 0° | 8° |
| All Dimensions in mm | | |

Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| X | 0.60 |
| Y | 1.55 |
| C1 | 5.4 |
| C2 | 1.27 |

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